

SOD-323 Plastic-Encapsulate ESD Protection Diodes

DESCRIPTION

The SD4V5TC TVS diode is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebooks, and PDA's. It offers superior electrical characteristics such as low clamping voltage, low leakage current and high surge capability. It is designed to protect sensitive electronic components which are connected to power lines, from over-stress caused by ESD (Electrostatic Discharge), EFT (Electrical Fast Transients) and Lighting.

The SD4V5TC is in a SOD-323 package and will protect one unidirectional line. It may be used to provide ESD protection up to ±30kV (Contact and air discharge) according to IEC61000-4-2, and withstand peak pulse current up to 160A (8/20µs) according to IEC61000-4-5.

Features

- ◆ Peak power dissipation: 3200W (8/20µs)
- ◆ Transient protection for high-speed data lines
- ◆ IEC61000-4-2 (ESD) ±30kV (air), ±30kV (contact)
- ◆ Low clamping voltage
- Low leakage current
- Working voltages: 4.5V
- Solid-state silicon-avalanche technology

Pin Configuration





Applications

- Power lines
- Personal digital assistants (PDA's)
- Microprocessors based equipment
- Notebooks, Desktops, and Servers
- Cell phone Handsets and Accessories
- Portable Electronics
- Peripherals

Circuit Diagram



Mechanical Characteristics

Device: SD4V5TCPackage: SOD-323

Marking: D4

Material: Halogen free and RoHS compliant

Flammability Rating: UL 94V-0

High temperature soldering guaranted:

260°C/ 10s

Packaging: Tape and Reel

◆ Reel size: 7 inch

Quantity per reel: 3,000pcs





Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	Vesd	± 30 ± 30	KV
Peak Pulse Power(tp=8/20us waveform)	P _{PP}	3200	W
Operating Temperature	T _{OPT}	−55 to +125	°C
Storage Temperature	Тѕтс	-55 to +150	°C
Lead Solder Temperature – Maximum (10 Second Duration)	TL	260(10 sec.)	°C

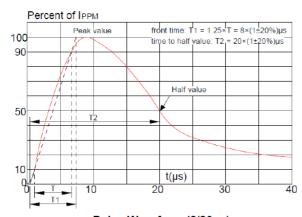
Electrical Characteristics (TA=25°C unless otherwise specified)

Symbol	Param	Test Condition	Min	Тур	Max	Units
V_{RWM}	Reverse Working Voltage				4.5	V
V_{BR}	Reverse Breakdown Voltage	I _T = 1mA	4.6	5.2	6.4	٧
I _R	Reverse Leakage Current	V _{RWM} = 4.5V			1	uA
I _{PP}	Peak Pulse Current	$t_p = 8/20 \mu s$			160	Α
	c Clamping Voltage	I_{PP} =50A, t_p = 8/20 μ s		8.5	11	V
V_{C}		$I_{PP} = 100A, t_p = 8/20\mu s$		12	14	V
		$I_{PP} = 160A, t_p = 8/20 \mu s$		17	20	V
CJ	Junction Capacitance	$V_R = 0V$, $f = 1MHz$		300	500	pF

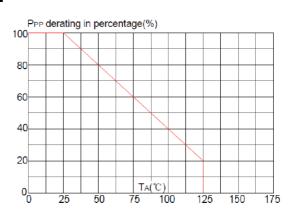
The above data are for reference only.



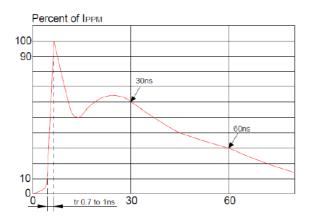
ELECTRICAL CHARACTERISTICS CURVE



Pulse Waveform (8/20us)



Pulse Derating Curve



ESD Clamping(8kV Contact Discharge)

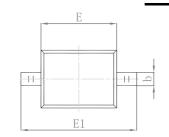
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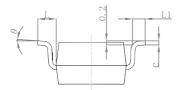


Outlitne Drawing

SOD-323 Package Outline Dimensions

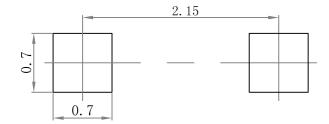






Symbol	Dimensions In	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	0.80	1.10	0.032	0.043	
A1	0.00	0.20	0.000	0.008	
A2	0.70	1.05	0.028	0.042	
b	0.20	0.40	0.007	0.016	
С	0.05	0.20	0.0019	0.0079	
D	1.10	1.45	0.043	0.057	
Е	1.40	1.80	0.063	0.070	
E1	2.50	2.80	0.098	0.110	
L	0.35	0.60	0.014	0.024	
L1	0.15	0.45	0.006	0.016	
θ	0°	9°	0°	9°	

Suggested Pad Layout



Note:

- 1. Controlling dimension: in/millimeters.
- 2.General tolerance: ±0.05mm.
- 3. The pad layout is for reference purposes only.

PACKAGE SPECIFICATIONS

Package	Reel Size	Reel DIA. (mm)	Q'TY/Reel (pcs)	Box Size (mm)	QTY/Box (pcs)	Carton Size (mm)	Q'TY/Carton (pcs)
SOD-323	7'	178	3000	183×188×80	45,000	386×265×215	180,000

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